

## II. Schottky Rectifier

### 1.0A Schottky Rectifier 1N5817~1N5819

(Package: DO-41)

<p><b>FEATURES</b></p> <ul style="list-style-type: none"> <li>• Plastic package has Underwriters Laboratory Flammability Classification 94V-0</li> <li>• Metal silicon junction, majority carrier conduction</li> <li>• Guardring for overvoltage protection</li> <li>• Low power loss, high efficiency</li> <li>• High current capability, low forward voltage drop</li> <li>• High surge capability</li> <li>• For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications</li> <li>• High temperature soldering guaranteed : 250 °C /10 seconds, 0.375"(9.5mm) lead length, 5 lbs. (2.3Kg) tension</li> </ul> <p><b>MECHANICAL DATA</b></p> <ul style="list-style-type: none"> <li>• Case : JEDEC DO-41 molded plastic body</li> <li>• Terminals : Plated axial leads, solderable per MIL-STD-750, Method 2026</li> <li>• Polarity : Color band denotes cathode end</li> <li>• Mounting Position : Any</li> <li>• Weight : 0.012 ounce, 0.33 grams</li> </ul>	<p>Case: DO-41 Dimensions in inches and (millimeters)</p>
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### Ratings & Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20%.

Characteristic	Symbol	1N5817	1N5818	1N5819	Units
Maximum repetitive peak reverse voltage	$V_{RRM}$	20	30	40	Volts
Maximum RMS voltage	$V_{RMS}$	14	21	28	Volts
Maximum DC blocking voltage	$V_{DC}$	20	30	40	Volts
Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_L = 90$	$I_O$	1.0			Amps
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	25.0			Amps
Maximum instantaneous forward voltage at 1.0 A	$V_F$	0.450	0.550	0.600	Volts
Maximum DC reverse current at rated DC blocking voltage $T_a = 25$ $T_a = 100$	$I_R$	1.0 10.0			mA
Typical junction capacitance (Note 1)	$C_j$	110.0			PF
Typical thermal resistance (Note 2)	$R_{th-JA}$	50			/ W
Operating junction and storage temperature range	$T_j, T_{stg}$	-65 to +125			

Notes:

1. Measured at 1.0 MHz and applied reverse voltage of 4.0 volts D.C.

2. Thermal resistance from junction to ambient 0.375"(9.5mm) lead length P.C.B. mounted

# Ratings and Characteristic Curves of 1N5817~1N5819

FIG. 1- FORWARD CURRENT DERATING CURVE

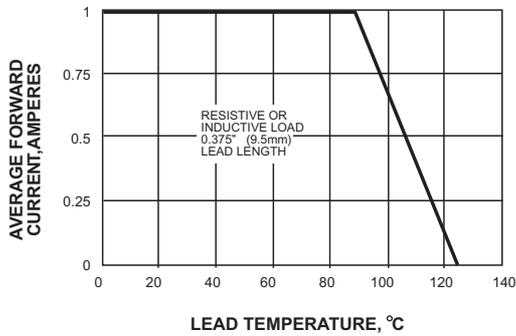


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

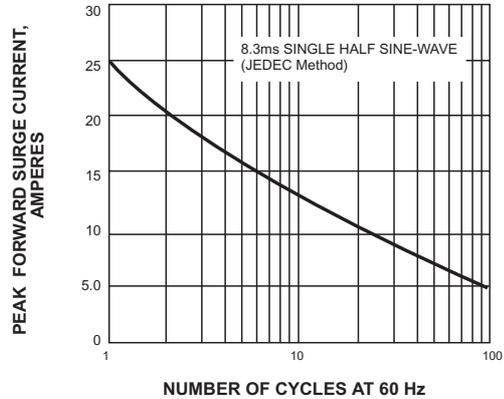


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

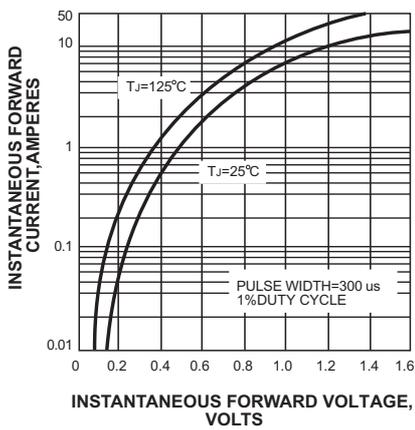


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

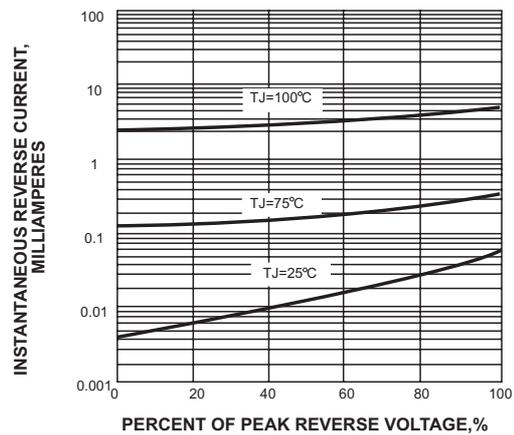


FIG. 5-TYPICAL JUNCTION CAPACITANCE

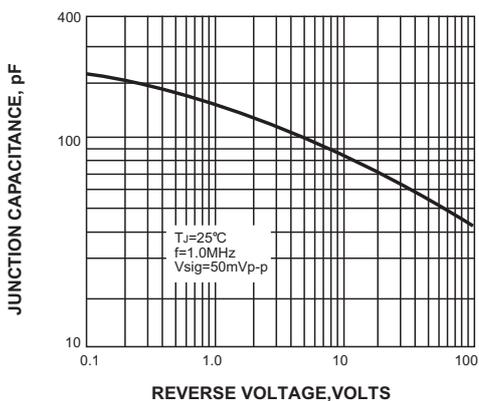


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

